## NSN 5961-01-111-5661

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-111-5661 **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-3 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 repetitive peak reverse voltage **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-collector pascal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Yes - demil/mli

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